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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

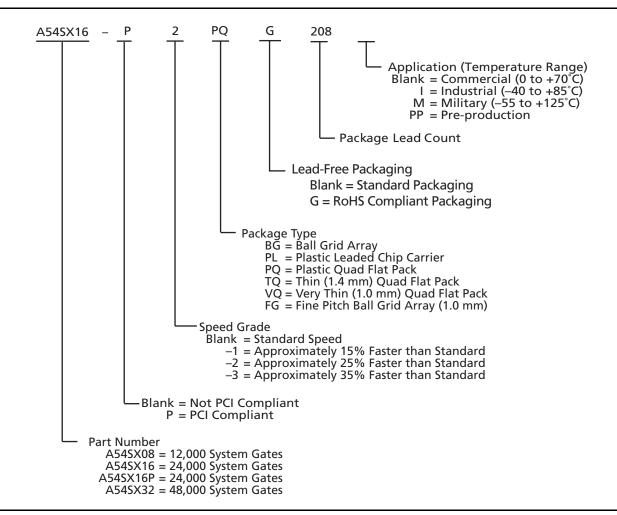
The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	1452
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	175
Number of Gates	24000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 125°C (TJ)
Package / Case	208-BFCQFP with Tie Bar
Supplier Device Package	208-CQFP (75x75)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a54sx16-1cq208b

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Ordering Information



Plastic Device Resources

	User I/Os (including clock buffers)										
Device	PLCC 84-Pin	VQFP 100-Pin	PQFP 208-Pin	TQFP 144-Pin	TQFP 176-Pin	PBGA 313-Pin	PBGA 329-Pin	FBGA 144-Pin			
A54SX08	69	81	130	113	128	_	_	111			
A54SX16	_	81	175	-	147	_	_	_			
A54SX16P	_	81	175	113	147	_	_	_			
A54SX32	_	-	174	113	147	249	249	_			

Note: Package Definitions (Consult your local Actel sales representative for product availability):

PLCC = Plastic Leaded Chip Carrier

PQFP = Plastic Quad Flat Pack

TQFP = Thin Quad Flat Pack

VQFP = Very Thin Quad Flat Pack

PBGA = Plastic Ball Grid Array

FBGA = Fine Pitch (1.0 mm) Ball Grid Array

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General Description

The Actel SX family of FPGAs features a sea-of-modules architecture that delivers device performance and integration levels not currently achieved by any other FPGA architecture. SX devices greatly simplify design time, enable dramatic reductions in design costs and power consumption, and further decrease time to market for performance-intensive applications.

The Actel SX architecture features two types of logic modules, the combinatorial cell (C-cell) and the register cell (R-cell), each optimized for fast and efficient mapping of synthesized logic functions. The routing and interconnect resources are in the metal layers above the logic modules, providing optimal use of silicon. This enables the entire floor of the device to be spanned with an uninterrupted grid of fine-grained, synthesis-friendly logic modules (or "sea-of-modules"), which reduces the distance signals have to travel between logic modules. To minimize signal propagation delay, SX devices employ both local and general routing resources. The high-speed local routing resources (DirectConnect and FastConnect) enable very fast local signal propagation that is optimal for fast counters, state machines, and datapath logic. The general system of segmented routing tracks allows any logic module in the array to be connected to any other logic or I/O module. Within this system, propagation delay is minimized by limiting the number of antifuse interconnect elements to five (90 percent of connections typically use only three antifuses). The unique local and general routing structure featured in SX devices gives fast and predictable performance, allows 100 percent pin-locking with full logic utilization, enables concurrent PCB development, reduces design time, and allows designers to achieve performance goals with minimum effort.

Further complementing SX's flexible routing structure is a hardwired, constantly loaded clock network that has been tuned to provide fast clock propagation with minimal clock skew. Additionally, the high performance of the internal logic has eliminated the need to embed latches or flip-flops in the I/O cells to achieve fast clock-to-out or fast input setup times. SX devices have easy to use I/O cells that do not require HDL instantiation, facilitating design reuse and reducing design and verification time.

SX Family Architecture

The SX family architecture was designed to satisfy nextgeneration performance and integration requirements for production-volume designs in a broad range of applications.

Programmable Interconnect Element

The SX family provides efficient use of silicon by locating the routing interconnect resources between the Metal 2 (M2) and Metal 3 (M3) layers (Figure 1-1 on page 1-2). This completely eliminates the channels of routing and interconnect resources between logic modules (as implemented on SRAM FPGAs and previous generations of antifuse FPGAs), and enables the entire floor of the device to be spanned with an uninterrupted grid of logic modules.

Interconnection between these logic modules is achieved using The Actel patented metal-to-metal programmable antifuse interconnect elements, which are embedded between the M2 and M3 layers. The antifuses are normally open circuit and, when programmed, form a permanent low-impedance connection.

The extremely small size of these interconnect elements gives the SX family abundant routing resources and provides excellent protection against design pirating. Reverse engineering is virtually impossible because it is extremely difficult to distinguish between programmed and unprogrammed antifuses, and there is no configuration bitstream to intercept.

Additionally, the interconnect elements (i.e., the antifuses and metal tracks) have lower capacitance and lower resistance than any other device of similar capacity, leading to the fastest signal propagation in the industry.

Logic Module Design

The SX family architecture is described as a "sea-of-modules" architecture because the entire floor of the device is covered with a grid of logic modules with virtually no chip area lost to interconnect elements or routing. The Actel SX family provides two types of logic modules, the register cell (R-cell) and the combinatorial cell (C-cell).

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The R-cell contains a flip-flop featuring asynchronous clear, asynchronous preset, and clock enable (using the S0 and S1 lines) control signals (Figure 1-2). The R-cell registers feature programmable clock polarity selectable on a register-by-register basis. This provides additional

flexibility while allowing mapping of synthesized functions into the SX FPGA. The clock source for the R-cell can be chosen from either the hardwired clock or the routed clock.

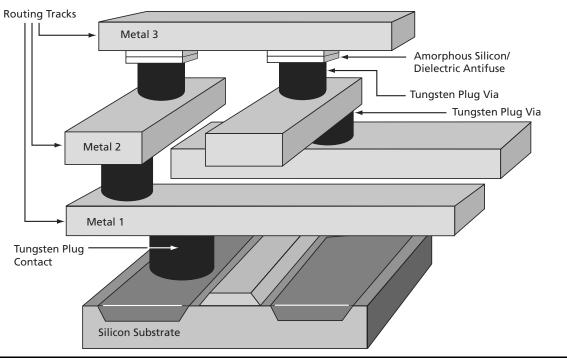


Figure 1-1 • SX Family Interconnect Elements

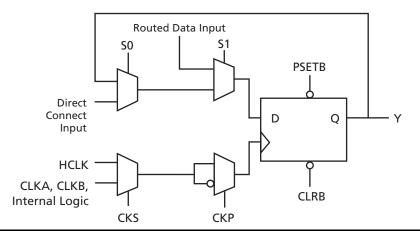


Figure 1-2 • R-Cell

The C-cell implements a range of combinatorial functions up to 5-inputs (Figure 1-3 on page 1-3). Inclusion of the DB input and its associated inverter function dramatically increases the number of combinatorial functions that can be implemented in a single module from 800 options in previous architectures to more than 4,000 in the SX architecture. An example of the improved flexibility

enabled by the inversion capability is the ability to integrate a 3-input exclusive-OR function into a single C-cell. This facilitates construction of 9-bit parity-tree functions with 2 ns propagation delays. At the same time, the C-cell structure is extremely synthesis friendly, simplifying the overall design and reducing synthesis time.

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Boundary Scan Testing (BST)

All SX devices are IEEE 1149.1 compliant. SX devices offer superior diagnostic and testing capabilities by providing Boundary Scan Testing (BST) and probing capabilities. These functions are controlled through the special test pins in conjunction with the program fuse. The functionality of each pin is described in Table 1-2. In the dedicated test mode, TCK, TDI, and TDO are dedicated pins and cannot be used as regular I/Os. In flexible mode, TMS should be set HIGH through a pull-up resistor of $10~\mathrm{k}\Omega$. TMS can be pulled LOW to initiate the test sequence.

The program fuse determines whether the device is in dedicated or flexible mode. The default (fuse not blown) is flexible mode.

Table 1-2 ● **Boundary Scan Pin Functionality**

Program Fuse Blown (Dedicated Test Mode)	Program Fuse Not Blown (Flexible Mode)				
TCK, TDI, TDO are dedicated BST pins.	TCK, TDI, TDO are flexible and may be used as I/Os.				
No need for pull-up resistor for TMS	Use a pull-up resistor of 10 k Ω on TMS.				

Dedicated Test Mode

In Dedicated mode, all JTAG pins are reserved for BST; designers cannot use them as regular I/Os. An internal pull-up resistor is automatically enabled on both TMS and TDI pins, and the TMS pin will function as defined in the IEEE 1149.1 (JTAG) specification.

To select Dedicated mode, users need to reserve the JTAG pins in Actel's Designer software by checking the "Reserve JTAG" box in "Device Selection Wizard" (Figure 1-7). JTAG pins comply with LVTTL/TTL I/O specification regardless of whether they are used as a user I/O or a JTAG I/O. Refer to the Table 1-5 on page 1-8 for detailed specifications.

Figure 1-7 • Device Selection Wizard

Development Tool Support

The SX family of FPGAs is fully supported by both the Actel Libero® Integrated Design Environment (IDE) and Designer FPGA Development software. Actel Libero IDE is a design management environment, seamlessly integrating design tools while guiding the user through the design flow, managing all design and log files, and passing necessary design data among tools. Libero IDE allows users to integrate both schematic and HDL synthesis into a single flow and verify the entire design in a single environment. Libero IDE includes Synplify® for Actel from Synplicity[®], ViewDraw[®] for Actel from Mentor Graphics[®], ModelSim[®] HDL Simulator from Mentor Graphics, WaveFormer Lite™ SynaptiCAD™, and Designer software from Actel. Refer to the Libero IDE flow diagram (located on the Actel website) for more information.

Actel Designer software is a place-and-route tool and provides a comprehensive suite of backend support tools for FPGA development. The Designer software includes timing-driven place-and-route, and a world-class integrated static timing analyzer and constraints editor. With the Designer software, a user can select and lock package pins while only minimally impacting the results of place-and-route. Additionally, the back-annotation flow is compatible with all the major simulators, and the simulation results can be cross-probed with Silicon Explorer II, Actel integrated verification and logic analysis tool. Another tool included in the Designer software is the SmartGen core generator, which easily creates popular and commonly used logic functions for implementation into your schematic or HDL design. Actel Designer software is compatible with the most popular FPGA design entry and verification tools from companies such as Mentor Graphics, Synplicity, Synopsys[®], and Cadence® Design Systems. The Designer software is available for both the Windows® and UNIX® operating systems.

Probe Circuit Control Pins

The Silicon Explorer II tool uses the boundary scan ports (TDI, TCK, TMS, and TDO) to select the desired nets for verification. The selected internal nets are assigned to the PRA/PRB pins for observation. Figure 1-8 on page 1-7 illustrates the interconnection between Silicon Explorer II and the FPGA to perform in-circuit verification.

Design Considerations

The TDI, TCK, TDO, PRA, and PRB pins should not be used as input or bidirectional ports. Because these pins are active during probing, critical signals input through these pins are not available while probing. In addition, the Security Fuse should not be programmed because doing so disables the Probe Circuitry.

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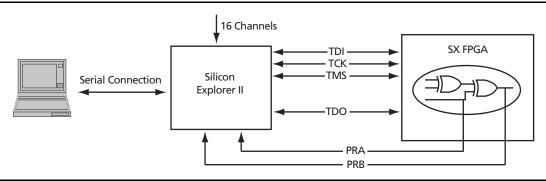


Figure 1-8 • Probe Setup

Programming

Device programming is supported through Silicon Sculptor series of programmers. In particular, Silicon Sculptor II are compact, robust, single-site and multi-site device programmer for the PC.

With standalone software, Silicon Sculptor II allows concurrent programming of multiple units from the same PC, ensuring the fastest programming times possible. Each fuse is subsequently verified by Silicon Sculptor II to insure correct programming. In addition, integrity tests ensure that no extra fuses are programmed. Silicon Sculptor II also provides extensive hardware self-testing capability.

The procedure for programming an SX device using Silicon Sculptor II are as follows:

- 1. Load the .AFM file
- 2. Select the device to be programmed
- 3. Begin programming

When the design is ready to go to production, Actel offers device volume-programming services either through distribution partners or via in-house programming from the factory.

For more details on programming SX devices, refer to the *Programming Antifuse Devices* application note and the *Silicon Sculptor II User's Guide*.

3.3 V / 5 V Operating Conditions

Table 1-3 • Absolute Maximum Ratings¹

Symbol	Parameter	Limits	Units
V _{CCR} ²	DC Supply Voltage ³	-0.3 to + 6.0	V
V_{CCA}^2	DC Supply Voltage	-0.3 to + 4.0	V
V _{CCI} ²	DC Supply Voltage (A54SX08, A54SX16, A54SX32)	-0.3 to + 4.0	V
V _{CCI} ²	DC Supply Voltage (A54SX16P)	-0.3 to + 6.0	V
V _I	Input Voltage	-0.5 to + 5.5	V
V _O	Output Voltage	-0.5 to + 3.6	V
I _{IO}	I/O Source Sink Current ³	−30 to + 5.0	mA
T _{STG}	Storage Temperature	–65 to +150	°C

Notes

- 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Device should not be operated outside the Recommended Operating Conditions.
- 2. V_{CCR} in the A54SX16P must be greater than or equal to V_{CCI} during power-up and power-down sequences and during normal operation.
- 3. Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than V_{CC} + 0.5 V or less than GND 0.5 V, the internal protection diodes will forward-bias and can draw excessive current.

Table 1-4 • Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range*	0 to + 70	-40 to + 85	-55 to +125	°C
3.3 V Power Supply Tolerance	±10	±10	±10	%V _{CC}
5.0 V Power Supply Tolerance	±5	±10	±10	%V _{CC}

Note: *Ambient temperature (T_A) is used for commercial and industrial; case temperature (T_C) is used for military.

Table 1-5 ● **Electrical Specifications**

	Commercial				Industrial		
Symbol	Parameter	Min.	Мах.	Min.	Max.	Units	
V _{OH}	(I _{OH} = -20 μA) (CMOS)	(V _{CCI} – 0.1)	V _{CCI}	(V _{CCI} – 0.1)	V _{CCI}	V	
	$(I_{OH} = -8 \text{ mA}) \text{ (TTL)}$	2.4	V_{CCI}				
	$(I_{OH} = -6 \text{ mA}) \text{ (TTL)}$			2.4	V_{CCI}		
V _{OL}	(I _{OL} = 20 μA) (CMOS)		0.10			V	
	$(I_{OL} = 12 \text{ mA}) \text{ (TTL)}$		0.50				
	$(I_{OL} = 8 \text{ mA}) \text{ (TTL)}$				0.50		
V_{IL}			8.0		0.8	V	
V_{IH}		2.0		2.0		V	
t _R , t _F	Input Transition Time t _R , t _F		50		50	ns	
C _{IO}	C _{IO} I/O Capacitance		10		10	pF	
I _{CC}	Standby Current, I _{CC}		4.0		4.0	mA	
$I_{CC(D)}$	I _{CC(D)} I _{Dynamic} V _{CC} Supply Current	See '	'Evaluating F	ower in SX Device	es" on page ´	1-16.	

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A54SX16P DC Specifications (3.3 V PCI Operation)

Table 1-8 • A54SX16P DC Specifications (3.3 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
V_{CCA}	Supply Voltage for Array		3.0	3.6	V
V_{CCR}	Supply Voltage required for Internal Biasing		3.0	3.6	V
V_{CCI}	Supply Voltage for I/Os		3.0	3.6	V
V_{IH}	Input High Voltage		0.5V _{CC}	$V_{CC} + 0.5$	V
V_{IL}	Input Low Voltage		-0.5	0.3V _{CC}	V
I _{IPU}	Input Pull-up Voltage ¹		0.7V _{CC}		V
I _{IL}	Input Leakage Current ²	$0 < V_{IN} < V_{CC}$		±10	μΑ
V_{OH}	Output High Voltage	I _{OUT} = -500 μA	0.9V _{CC}		V
V_{OL}	Output Low Voltage	I _{OUT} = 1500 μA		0.1V _{CC}	V
C _{IN}	Input Pin Capacitance ³			10	pF
C _{CLK}	CLK Pin Capacitance		5	12	pF
C _{IDSEL}	IDSEL Pin Capacitance ⁴			8	pF

Notes:

- 1. This specification should be guaranteed by design. It is the minimum voltage to which pull-up resistors are calculated to pull a floated network. Applications sensitive to static power utilization should assure that the input buffer is conducting minimum current at this input voltage.
- 2. Input leakage currents include hi-Z output leakage for all bidirectional buffers with tristate outputs.
- 3. Absolute maximum pin capacitance for a PCI input is 10 pF (except for CLK).
- 4. Lower capacitance on this input-only pin allows for non-resistive coupling to AD[xx].

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Power-Up Sequencing

Table 1-10 • Power-Up Sequencing

V _{CCA}	V _{CCR}	V _{CCI}	Power-Up Sequence	Comments
A54SX08, A545	SX16, A54SX32			
3.3 V			5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	Possible damage to device
A54SX16P				
3.3 V	3.3 V	3.3 V	3.3 V Only	No possible damage to device
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	Possible damage to device
3.3 V	5.0 V	5.0 V	5.0 V First 3.3 V Second	No possible damage to device
			3.3 V First 5.0 V Second	No possible damage to device

Note: No inputs should be driven (high or low) before completion of power-up.

Power-Down Sequencing

Table 1-11 • Power-Down Sequencing

V _{CCA}	V _{CCR}	V _{CCI}	Power-Down Sequence	Comments							
A54SX08, A54S	A54SX08, A54SX16, A54SX32										
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	Possible damage to device							
			3.3 V First 5.0 V Second	No possible damage to device							
A54SX16P			•	_							
3.3 V	3.3 V	3.3 V	3.3 V Only	No possible damage to device							
3.3 V	5.0 V	3.3 V	5.0 V First 3.3 V Second	Possible damage to device							
			3.3 V First 5.0 V Second	No possible damage to device							
3.3 V	5.0 V	5.0 V	5.0 V First 3.3 V Second	No possible damage to device							
			3.3 V First 5.0 V Second	No possible damage to device							

Note: No inputs should be driven (high or low) after the beginning of the power-down sequence.

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Table 1-15 ● Package Thermal Characteristics

Package Type	Pin Count	$\theta_{ extsf{jc}}$	θ _{ja} Still Air	$_{ m j_a}^{ heta_{ m ja}}$ 300 ft/min.	Units
Plastic Leaded Chip Carrier (PLCC)	84	12	32	22	°C/W
Thin Quad Flat Pack (TQFP)	144	11	32	24	°C/W
Thin Quad Flat Pack (TQFP)	176	11	28	21	°C/W
Very Thin Quad Flatpack (VQFP)	100	10	38	32	°C/W
Plastic Quad Flat Pack (PQFP) without Heat Spreader	208	8	30	23	°C/W
Plastic Quad Flat Pack (PQFP) with Heat Spreader	208	3.8	20	17	°C/W
Plastic Ball Grid Array (PBGA)	272	3	20	14.5	°C/W
Plastic Ball Grid Array (PBGA)	313	3	23	17	°C/W
Plastic Ball Grid Array (PBGA)	329	3	18	13.5	°C/W
Fine Pitch Ball Grid Array (FBGA)	144	3.8	38.8	26.7	°C/W

Note: SX08 does not have a heat spreader.

Table 1-16 • Temperature and Voltage Derating Factors*

	Junction Temperature									
V _{CCA}	-55	-40	0	25	70	85	125			
3.0	0.75	0.78	0.87	0.89	1.00	1.04	1.16			
3.3	0.70	0.73	0.82	0.83	0.93	0.97	1.08			
3.6	0.66	0.69	0.77	0.78	0.87	0.92	1.02			

Note: *Normalized to worst-case commercial, $T_J = 70$ °C, $V_{CCA} = 3.0 \text{ V}$

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A54SX16 Timing Characteristics

Table 1-18 • A54SX16 Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

	(Norse case commercial conditions, t		Speed		Speed	'-1' \$	Speed	'Std'	Speed	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
C-Cell Propa	agation Delays ¹									
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{RD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{RD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{RD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns
R-Cell Timir	ıg									
t _{RCO}	Sequential Clock-to-Q		0.8		1.1		1.2		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		8.0	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.5		0.7		8.0		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ile Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{IRD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{IRD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{IRD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns

Notes:

- 1. For dual-module macros, use $t_{PD}+t_{RD1}+t_{PDn},\ t_{RCO}+t_{RD1}+t_{PDn},\ or\ t_{PD1}+t_{RD1}+t_{SUD},\ whichever\ is\ appropriate.$
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.
- 3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} , the loading is 5 pF.

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A54SX16P Timing Characteristics

Table 1-19 • A54SX16P Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA},V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' \$	Speed	'-2' \$	Speed	'-1' \$	Speed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Max.	Min.	Max.	Min.	Мах.	Units
C-Cell Propagation Delays ¹										
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{RD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{RD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{RD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns
R-Cell Timir	ng									
t _{RCO}	Sequential Clock-to-Q		0.9		1.1		1.3		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		0.8	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.5		0.7		0.8		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ıle Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{IRD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{IRD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{IRD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

3. Delays based on 10 pF loading.

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Table 1-19 • A54SX16P Timing Characteristics (Continued) (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' S	peed	'-2' 9	peed	'-1' \$	peed	'Std'	Speed	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
TTL/PCI Out	out Module Timing									
t _{DLH}	Data-to-Pad LOW to HIGH		1.5		1.7		2.0		2.3	ns
t _{DHL}	Data-to-Pad HIGH to LOW		1.9		2.2		2.4		2.9	ns
t _{ENZL}	Enable-to-Pad, Z to L		2.3		2.6		3.0		3.5	ns
t _{ENZH}	Enable-to-Pad, Z to H		1.5		1.7		1.9		2.3	ns
t _{ENLZ}	Enable-to-Pad, L to Z		2.7		3.1		3.5		4.1	ns
t _{ENHZ}	Enable-to-Pad, H to Z		2.9		3.3		3.7		4.4	ns
PCI Output	Module Timing ³									
t _{DLH}	Data-to-Pad LOW to HIGH		1.8		2.0		2.3		2.7	ns
t _{DHL}	Data-to-Pad HIGH to LOW		1.7		2.0		2.2		2.6	ns
t _{ENZL}	Enable-to-Pad, Z to L		8.0		1.0		1.1		1.3	ns
t _{ENZH}	Enable-to-Pad, Z to H		1.2		1.2		1.5		1.8	ns
t _{ENLZ}	Enable-to-Pad, L to Z		1.0		1.1		1.3		1.5	ns
t _{ENHZ}	Enable-to-Pad, H to Z		1.1		1.3		1.5		1.7	ns
TTL Output	Module Timing									
t _{DLH}	Data-to-Pad LOW to HIGH		2.1		2.5		2.8		3.3	ns
t _{DHL}	Data-to-Pad HIGH to LOW		2.0		2.3		2.6		3.1	ns
t _{ENZL}	Enable-to-Pad, Z to L		2.5		2.9		3.2		3.8	ns
t _{ENZH}	Enable-to-Pad, Z to H		3.0		3.5		3.9		4.6	ns
t _{ENLZ}	Enable-to-Pad, L to Z		2.3		2.7		3.1		3.6	ns
t _{ENHZ}	Enable-to-Pad, H to Z		2.9		3.3		3.7		4.4	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

3. Delays based on 10 pF loading.

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Table 1-20 • A54SX32 Timing Characteristics (Continued)
(Worst-Case Commercial Conditions, V_{CCR}= 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' 9	Speed	'-2' \$	Speed	'-1' 9	peed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
Dedicated (Hardwired) Array Clock Network									
t _{HCKH}	Input LOW to HIGH (pad to R-Cell input)		1.9		2.1		2.4		2.8	ns
t _{HCKL}	Input HIGH to LOW (pad to R-Cell input)		1.9		2.1		2.4		2.8	ns
t _{HPWH}	Minimum Pulse Width HIGH	1.4		1.6		1.8		2.1		ns
t _{HPWL}	Minimum Pulse Width LOW	1.4		1.6		1.8		2.1		ns
t _{HCKSW}	Maximum Skew		0.3		0.4		0.4		0.5	ns
t _{HP}	Minimum Period	2.7		3.1		3.6		4.2		ns
f _{HMAX}	Maximum Frequency		350		320		280		240	MHz
Routed Arra	ay Clock Networks									
t _{RCKH}	Input LOW to HIGH (light load) (pad to R-Cell input)		2.4		2.7		3.0		3.5	ns
t _{RCKL}	Input HIGH to LOW (light load) (pad to R-Cell input)		2.4		2.7		3.1		3.6	ns
t _{RCKH}	Input LOW to HIGH (50% load) (pad to R-Cell input)		2.7		3.0		3.5		4.1	ns
t _{RCKL}	Input HIGH to LOW (50% load) (pad to R-Cell input)		2.7		3.1		3.6		4.2	ns
t _{RCKH}	Input LOW to HIGH (100% load) (pad to R-Cell input)		2.7		3.1		3.5		4.1	ns
t _{RCKL}	Input HIGH to LOW (100% load) (pad to R-Cell input)		2.8		3.2		3.6		4.3	ns
t _{RPWH}	Min. Pulse Width HIGH	2.1		2.4		2.7		3.2		ns
t _{RPWL}	Min. Pulse Width LOW	2.1		2.4		2.7		3.2		ns
t _{RCKSW}	Maximum Skew (light load)		0.85		0.98		1.1		1.3	ns
t _{RCKSW}	Maximum Skew (50% load)		1.23		1.4		1.6		1.9	ns
t _{RCKSW}	Maximum Skew (100% load)		1.30		1.5		1.7		2.0	ns
TTL Output	Module Timing ³									
t _{DLH}	Data-to-Pad LOW to HIGH		1.6		1.9		2.1		2.5	ns
t _{DHL}	Data-to-Pad HIGH to LOW		1.6		1.9		2.1		2.5	ns
t _{ENZL}	Enable-to-Pad, Z to L		2.1		2.4		2.8		3.2	ns
t _{ENZH}	Enable-to-Pad, Z to H		2.3		2.7		3.1		3.6	ns
t _{ENLZ}	Enable-to-Pad, L to Z		1.4		1.7		1.9		2.2	ns
t _{ENHZ}	Enable-to-Pad, H to Z		1.3		1.5		1.7		2.0	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn} , t_{RCO} + t_{RD1} + t_{PDn} , or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.

3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} the loading is 5 pF.

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144-Pin TQFP				
Pin Number	A54SX08 Function	A54SX16P Function	A54SX32 Function	
73	GND	GND	GND	
74	I/O	1/0	I/O	
75	I/O	I/O	I/O	
76	I/O	I/O	I/O	
77	I/O	I/O	I/O	
78	I/O	I/O	I/O	
79	V_{CCA}	V_{CCA}	V_{CCA}	
80	V _{CCI}	V _{CCI}	V_{CCI}	
81	GND	GND	GND	
82	I/O	I/O	I/O	
83	I/O	I/O	I/O	
84	I/O	I/O	I/O	
85	I/O	I/O	I/O	
86	I/O	1/0	I/O	
87	I/O	1/0	I/O	
88	I/O	1/0	I/O	
89	V _{CCA}	V _{CCA}	V _{CCA}	
90	V_{CCR}	V_{CCR}	V_{CCR}	
91	I/O	1/0	I/O	
92	I/O	1/0	I/O	
93	I/O	1/0	I/O	
94	I/O	1/0	I/O	
95	I/O	1/0	I/O	
96	I/O	1/0	I/O	
97	I/O	I/O	I/O	
98	V_{CCA}	V_{CCA}	V_{CCA}	
99	GND	GND	GND	
100	I/O	I/O	I/O	
101	GND	GND	GND	
102	V _{CCI}	V _{CCI}	V _{CCI}	
103	I/O	I/O	I/O	
104	I/O	1/0	I/O	
105	I/O	1/0	I/O	
106	I/O	1/0	I/O	
107	I/O	1/0	I/O	
108	I/O	I/O	I/O	

144-Pin TQFP					
Pin Number	A54SX08 Function	A54SX16P Function	A54SX32 Function		
109	GND	GND	GND		
110	I/O	1/0	I/O		
111	I/O	1/0	1/0		
112	I/O	1/0	I/O		
113	I/O	1/0	I/O		
114	I/O	1/0	1/0		
115	V _{CCI}	V _{CCI}	V _{CCI}		
116	I/O	I/O	I/O		
117	I/O	1/0	I/O		
118	I/O	1/0	I/O		
119	I/O	1/0	I/O		
120	I/O	1/0	I/O		
121	I/O	1/0	I/O		
122	I/O	1/0	I/O		
123	I/O	1/0	I/O		
124	I/O	I/O	I/O		
125	CLKA	CLKA	CLKA		
126	CLKB	CLKB	CLKB		
127	V_{CCR}	V_{CCR}	V_{CCR}		
128	GND	GND	GND		
129	V_{CCA}	V_{CCA}	V_{CCA}		
130	I/O	I/O	I/O		
131	PRA, I/O	PRA, I/O	PRA, I/O		
132	I/O	I/O	I/O		
133	I/O	I/O	I/O		
134	I/O	I/O	I/O		
135	I/O	I/O	I/O		
136	I/O	I/O	I/O		
137	I/O	I/O	I/O		
138	I/O	I/O	I/O		
139	I/O	I/O	I/O		
140	V _{CCI}	V _{CCI}	V _{CCI}		
141	I/O	I/O	I/O		
142	I/O	I/O	I/O		
143	I/O	1/0	I/O		
144	TCK, I/O	TCK, I/O	TCK, I/O		

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176-Pin TQFP					
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function		
1	GND	GND	GND		
2	TDI, I/O	TDI, I/O	TDI, I/O		
3	NC	1/0	I/O		
4	I/O	1/0	I/O		
5	I/O	1/0	I/O		
6	I/O	1/0	I/O		
7	I/O	1/0	I/O		
8	I/O	1/0	I/O		
9	I/O	I/O	I/O		
10	TMS	TMS	TMS		
11	V _{CCI}	V _{CCI}	V _{CCI}		
12	NC	I/O	I/O		
13	I/O	I/O	I/O		
14	I/O	1/0	I/O		
15	I/O	I/O	I/O		
16	I/O	I/O	I/O		
17	I/O	I/O	I/O		
18	I/O	I/O	I/O		
19	I/O	I/O	I/O		
20	I/O	1/0	I/O		
21	GND	GND	GND		
22	V _{CCA}	V _{CCA}	V _{CCA}		
23	GND	GND	GND		
24	I/O	I/O	I/O		
25	I/O	I/O	I/O		
26	I/O	I/O	I/O		
27	I/O	I/O	I/O		
28	I/O	I/O	I/O		
29	I/O	I/O	I/O		
30	I/O	I/O	I/O		
31	I/O	I/O	I/O		
32	V _{CCI}	V _{CCI}	V _{CCI}		
33	V _{CCA}	V _{CCA}	V _{CCA}		
34	I/O	1/0	1/0		

176-Pin TQFP					
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function		
35	I/O	1/0	1/0		
36	I/O	I/O	1/0		
37	I/O	1/0	I/O		
38	I/O	I/O	1/0		
39	I/O	I/O	1/0		
40	NC	I/O	1/0		
41	I/O	I/O	1/0		
42	NC	I/O	I/O		
43	I/O	I/O	1/0		
44	GND	GND	GND		
45	I/O	I/O	1/0		
46	I/O	I/O	1/0		
47	I/O	I/O	1/0		
48	I/O	I/O	I/O		
49	I/O	I/O	I/O		
50	I/O	I/O	1/0		
51	I/O	1/0	1/0		
52	V _{CCI}	V _{CCI}	V _{CCI}		
53	I/O	1/0	1/0		
54	NC	1/0	1/0		
55	I/O	1/0	1/0		
56	I/O	1/0	1/0		
57	NC	1/0	1/0		
58	I/O	1/0	1/0		
59	I/O	1/0	1/0		
60	I/O	1/0	1/0		
61	1/0	1/0	1/0		
62	1/0	1/0	I/O		
63	1/0	I/O	1/0		
64	PRB, I/O	PRB, I/O	PRB, I/O		
65	GND	GND	GND		
66	V _{CCA}	V _{CCA}	V _{CCA}		
67	V_{CCR}	V_{CCR}	V_{CCR}		
68	I/O	1/0	I/O		

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313-Pin PBGA

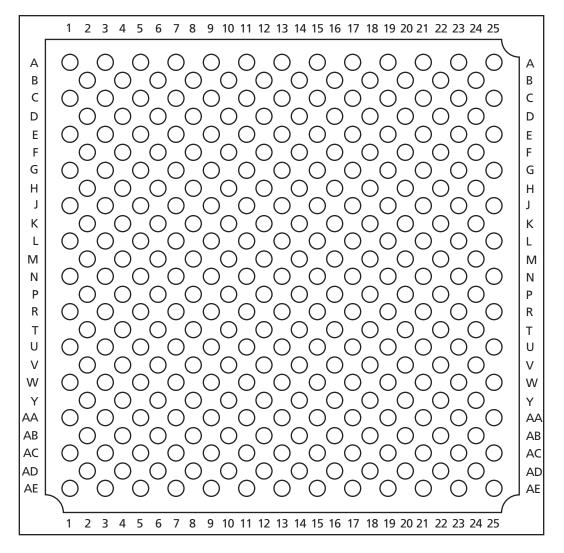


Figure 2-6 • 313-Pin PBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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329-Pin PBGA

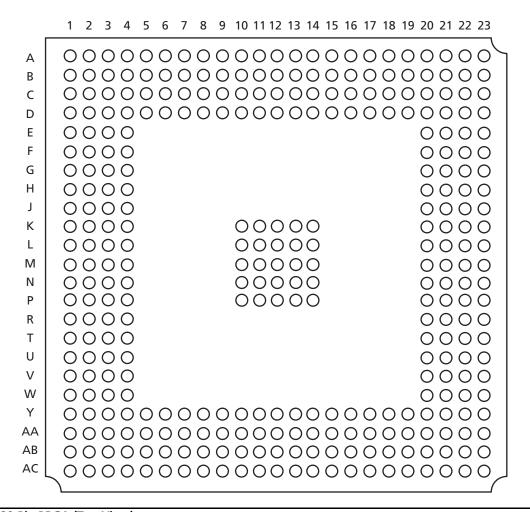


Figure 2-7 • 329-Pin PBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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329-Pin PBGA			
Pin Number	A54SX32 Function		
A1	GND		
A2	GND		
А3	V _{CCI}		
A4	NC		
A5	I/O		
A6	I/O		
A7	V _{CCI}		
A8	NC		
A9	I/O		
A10	I/O		
A11	I/O		
A12	I/O		
A13	CLKB		
A14	I/O		
A15	I/O		
A16	I/O		
A17	I/O		
A18	1/0		
A19	I/O		
A20	I/O		
A21	NC		
A22	V _{CCI}		
A23	GND		
AA1	V _{CCI}		
AA2	I/O		
AA3	GND		
AA4	I/O		
AA5	1/0		
AA6	I/O		
AA7	I/O		
AA8	I/O		
AA9	I/O		
AA10	I/O		
AA11	I/O		
AA12	1/0		

	n PBGA			
Pin Number	A54SX32 Function			
AA13	1/0			
AA14	I/O			
AA15	I/O			
AA16	I/O			
AA17	1/0			
AA18	I/O			
AA19	I/O			
AA20	TDO, I/O			
AA21	V _{CCI}			
AA22	1/0			
AA23	V _{CCI}			
AB1	1/0			
AB2	GND			
AB3	1/0			
AB4	1/0			
AB5	1/0			
AB6	1/0			
AB7	1/0			
AB8	1/0			
AB9	1/0			
AB10	1/0			
AB11	PRB, I/O			
AB12	1/0			
AB13	HCLK			
AB14	1/0			
AB15	1/0			
AB16	1/0			
AB17	1/0			
AB18	1/0			
AB19	1/0			
AB20	I/O			
AB21	I/O			
AB22	GND			
AB23	1/0			
AC1	GND			

329-Pin PBGA			
Pin Number	A54SX32 Function		
AC2	V _{CCI}		
AC3	NC		
AC4	1/0		
AC5	I/O		
AC6	I/O		
AC7	I/O		
AC8	I/O		
AC9	V _{CCI}		
AC10	I/O		
AC11	I/O		
AC12	I/O		
AC13	I/O		
AC14	I/O		
AC15	NC		
AC16	I/O		
AC17	I/O		
AC18	I/O		
AC19	I/O		
AC20	I/O		
AC21	NC		
AC22	V _{CCI}		
AC23	GND		
B1	V _{CCI}		
B2	GND		
В3	I/O		
В4	I/O		
B5	I/O		
В6	I/O		
В7	I/O		
B8	I/O		
В9	I/O		
B10	I/O		
B11	I/O		
B12	PRA, I/O		
B13	CLKA		

329-Pin PBGA				
Pin Number	A54SX32 Function			
B14	1/0			
B15	1/0			
B16				
	1/0			
B17	1/0			
B18	1/0			
B19	I/O			
B20	I/O			
B21	I/O			
B22	GND			
B23	V _{CCI}			
C1	NC			
C2	TDI, I/O			
C3	GND			
C4	I/O			
C5	I/O			
C6	I/O			
C7	I/O			
C8	I/O			
С9	I/O			
C10	I/O			
C11	I/O			
C12	I/O			
C13	I/O			
C14	I/O			
C15	I/O			
C16	I/O			
C17	I/O			
C18	I/O			
C19	I/O			
C20	I/O			
C21	V _{CCI}			
C22	GND			
C23	NC			
D1	I/O			
D2	I/O			

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